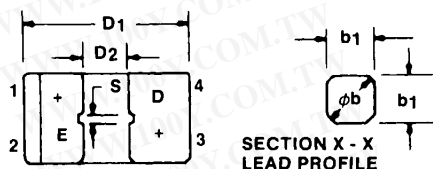
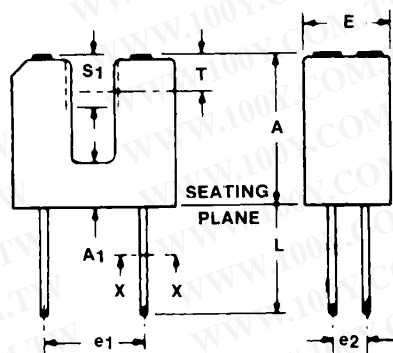


PACKAGE DIMENSIONS



ST1340-01



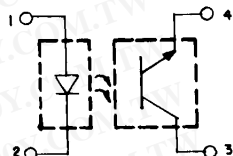
ST1340-02

| SYMBOL | MILLIMETERS | | INCHES | | NOTES |
|----------------|-------------|------|-----------|------|-------|
| | MIN. | MAX. | MIN. | MAX. | |
| A | 10.7 | 11.0 | .422 | .433 | |
| A ₁ | 3.0 | 3.2 | .119 | .125 | |
| ∅b | .600 | .750 | .024 | .030 | 2 |
| b ₁ | .50 NOM. | | .020 NOM. | | 2 |
| D ₁ | 11.6 | 12.0 | .457 | .472 | |
| D ₂ | 3.0 | 3.3 | .119 | .129 | |
| e ₁ | 6.9 | 7.5 | .272 | .295 | |
| e ₂ | 2.3 | 2.8 | .091 | .110 | |
| E | 6.15 | 6.35 | .243 | .249 | |
| L | 8.00 | | .315 | | |
| S | .85 | | .034 | | .039 |
| S ₁ | 3.45 | 3.75 | .136 | .147 | |
| T | 2.6 NOM. | | .103 NOM. | | 3 |

NOTES:

1. INCH DIMENSIONS ARE DERIVED FROM MILLIMETERS.
2. FOUR LEADS. LEAD CROSS SECTION IS CONTROLLED BETWEEN 1.27mm (.050") FROM SEATING PLANE AND THE END OF THE LEADS.
3. THE SENSING AREA IS DEFINED BY THE "S" DIMENSION AND BY DIMENSION "T" ±0.75mm (±.030 INCH).

PACKAGE OUTLINE



ST1609

DESCRIPTION

The H22A Slotted Optical Switch is a gallium arsenide light emitting diode coupled to a silicon photodarlington in a plastic housing. The packaging system is designed to optimize the mechanical resolution, coupling efficiency, ambient light rejection, cost and reliability. The gap in the housing provides a means of interrupting the signal with an opaque material, switching the output from an "ON" to an "OFF" state.

FEATURES

- Opaque housing
- Low cost
- .035" apertures
- High I_{C(ON)}

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

| | |
|-------------------------|-------------------------------------|
| Storage Temperature | -55°C to +100°C |
| Operating Temperature | -55°C to +100°C |
| Soldering: | |
| Lead Temperature (Iron) | 240°C for 5 sec. ^(3,4,5) |
| Lead Temperature (Flow) | 260°C for 10 sec. ^(3,4) |

INPUT DIODE

| | |
|----------------------------|-----------------------|
| Continuous Forward Current | 60 mA |
| Reverse Voltage | 6.0 Volts |
| Power Dissipation | 100 mW ⁽¹⁾ |

OUTPUT TRANSISTOR

| | |
|---------------------------|-----------------------|
| Collector-Emitter Voltage | 30 Volts |
| Emitter-Collector Voltage | 6 Volts |
| Power Dissipation | 150 mW ⁽²⁾ |

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
|-----------------------------|---------------|------|-------------|------|---------------|---------------------------------|
| INPUT DIODE | | | | | | |
| Forward Voltage | V_F | — | 1.7 | — | V | $I_F = 60\text{ mA}$ |
| Reverse Breakdown Voltage | V_R | 6.0 | — | — | V | $I_R = 10\mu\text{A}$ |
| Reverse Leakage Current | I_R | — | — | 1.0 | μA | $V_R = 3\text{ V}$ |
| OUTPUT TRANSISTOR | | | | | | |
| Emitter-Collector Breakdown | BV_{ECO} | 6.0 | — | — | V | $I_E = 100\mu\text{A}, E_e = 0$ |
| Collector-Emitter Breakdown | BV_{CEO} | 30 | — | — | V | $I_C = 1\text{ mA}, E_e = 0$ |
| Collector-Emitter Leakage | I_{CEO} | — | — | 100 | nA | $V_{CE} = 25\text{ V}, E_e = 0$ |
| COUPLED | | | | | | |
| On-State Collector Current | $I_{C(ON)}$ | — | See page 3. | — | mA | |
| Saturation Voltage | $V_{CE(SAT)}$ | — | See page 3. | — | V | |
| Turn-On Time | t_{on} | — | See page 3. | — | μS | |
| Turn-Off Time | t_{off} | — | See page 3. | — | μS | |

NOTES

1. Derate power dissipation linearly 1.33 mW/°C above 25°C.
2. Derate power dissipation linearly 2.00 mW/°C above 25°C.
3. RMA flux is recommended.
4. Methanol or Isopropyl alcohols are recommended as cleaning agents.
5. Soldering iron tip $\frac{1}{16}$ " (1.6 mm) from housing.

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

FAIRCHILD
 SEMICONDUCTOR™

SLOTTED OPTICAL SWITCH

| $I_{C(ON)}$, $V_{CE(SAT)}$, t_{on} AND t_{off} | | | | | | |
|---|---------------|------|------|------|---------|---|
| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
| ON-STATE COLLECTOR CURRENT | | | | | | |
| H22A1 | $I_{C(ON)}$ | 0.15 | — | — | mA | $I_F = 5mA, V_{CE} = 5V$ |
| H22A2 | $I_{C(ON)}$ | 0.30 | — | — | mA | $I_F = 5mA, V_{CE} = 5V$ |
| H22A3 | $I_{C(ON)}$ | 0.60 | — | — | mA | $I_F = 5mA, V_{CE} = 5V$ |
| H22A1 | $I_{C(ON)}$ | 1.0 | — | — | mA | $I_F = 20mA, V_{CE} = 5V$ |
| H22A2 | $I_{C(ON)}$ | 2.0 | — | — | mA | $I_F = 20mA, V_{CE} = 5V$ |
| H22A3 | $I_{C(ON)}$ | 4.0 | — | — | mA | $I_F = 20mA, V_{CE} = 5V$ |
| H22A1 | $I_{C(ON)}$ | 1.9 | — | — | mA | $I_F = 30mA, V_{CE} = 5V$ |
| H22A2 | $I_{C(ON)}$ | 3.0 | — | — | mA | $I_F = 30mA, V_{CE} = 5V$ |
| H22A3 | $I_{C(ON)}$ | 5.5 | — | — | mA | $I_F = 30mA, V_{CE} = 5V$ |
| SATURATION VOLTAGE | | | | | | |
| H22A2 | $V_{CE(SAT)}$ | — | — | 0.40 | V | $I_F = 20mA, I_C = 1.8mA$ |
| H22A3 | $V_{CE(SAT)}$ | — | — | 0.40 | V | $I_F = 20mA, I_C = 1.8mA$ |
| H22A1 | $V_{CE(SAT)}$ | — | — | 0.40 | V | $I_F = 30mA, I_C = 1.8mA$ |
| Turn-On Time | t_{on} | — | 8 | — | μS | $V_{CC} = 5V, I_F = 30mA, R_L = 2.5K\Omega$ |
| Turn-Off Time | t_{off} | — | 50 | — | μS | $V_{CC} = 5V, I_F = 30mA, R_L = 2.5K\Omega$ |

TYPICAL CHARACTERISTICS

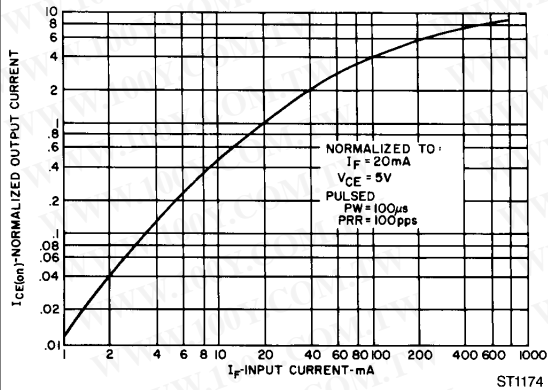


Fig. 1. Output Current vs. Input Current

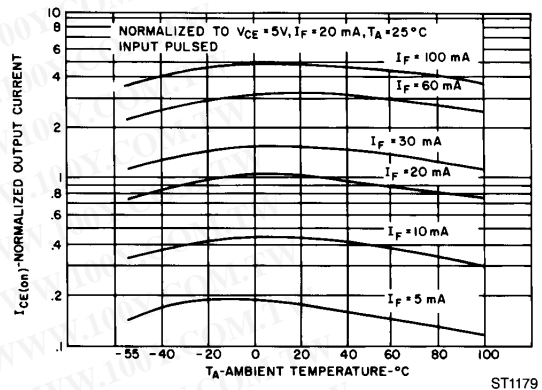


Fig. 2. Output Current vs. Temperature

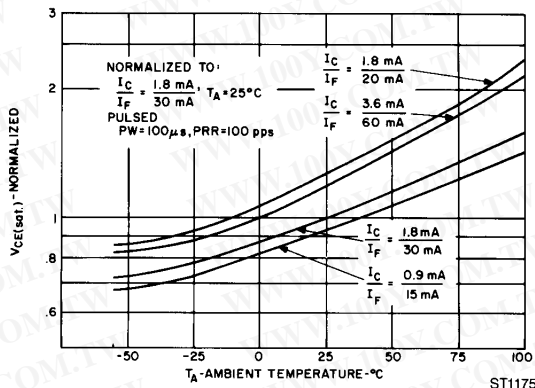


Fig. 3. $V_{CE(SAT)}$ vs. Temperature

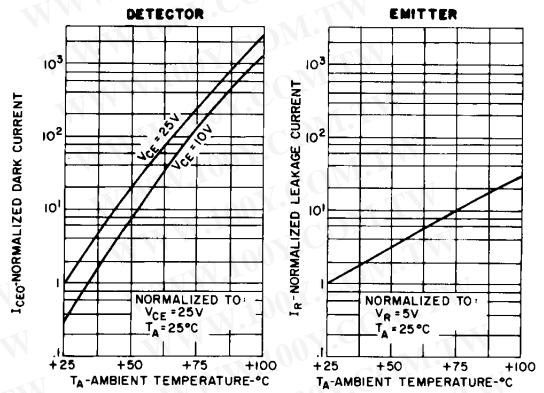


Fig. 4. Leakage Currents vs. Temperature

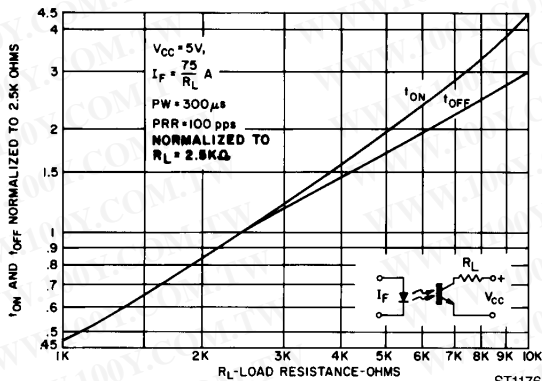


Fig. 5. Switching Speed vs. R_L

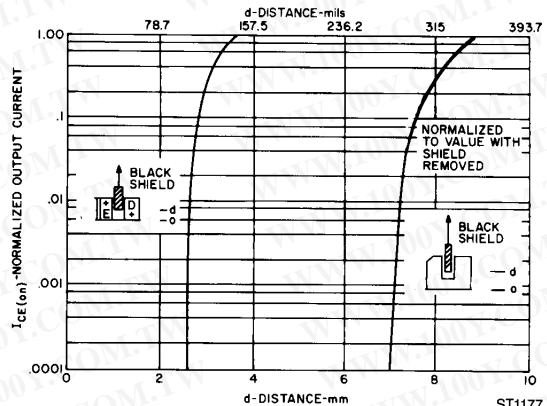


Fig. 6. Output Current vs. Shield Distance

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

勝特力材料 886-3-5753170
勝特力电子(上海) 86-21-54151736
勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)